Thyristor Semiconductor Device - Page 1 of 1



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Inclo	sure Material:	
Meta	I	
Over	all Length:	
0.565	5 inches	
Over	all Diameter:	
1.650	) inches	
Inter	nal Configuration:	
Junct	tion contact	
Mou	nting Method:	
Press	s fit	
Featu	ures Provided:	
Herm	netically sealed case	
Semi	iconductor Material:	
Silico	n	
Volta	ge Rating In Volts Per Characteristic:	
2.6 c	on-state voltage, dc	
Curre	ent Rating Per Characteristic:	
180.0	00 amperes on-state current, dc	
Maxi	mum Operating Tempurature Per Measurement Point:	
125.0	) degrees celsius junction	
Spec	ial Features:	
Interr	nal junction configuration, pnpnp	
Term	inal Type And Quantity:	
3 uni	nsulated wire lead w/terminal lug	
Shelf	f Life:	
N/a		
Unit	Of Measure:	
Demi	ilitarization:	
No		
Fiig:		
A110	a0	